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FQP7P06 P-Channel QFET[®] MOSFET -60 V, -7 A, 410 mΩ

Description

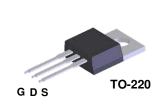
This P-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor®'s proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

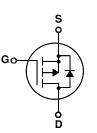
March 2013

FQP7P06 P-Channel MOSFET

Features

- -7 A, -60 V, $R_{DS(on)}$ =410 m $\Omega(Max.)$ @V_{GS}=-10 V, I_D=-3.5 A
- Low Gate Charge (Typ. 6.3 nC)
- Low Crss (Typ. 25 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temperature Rating





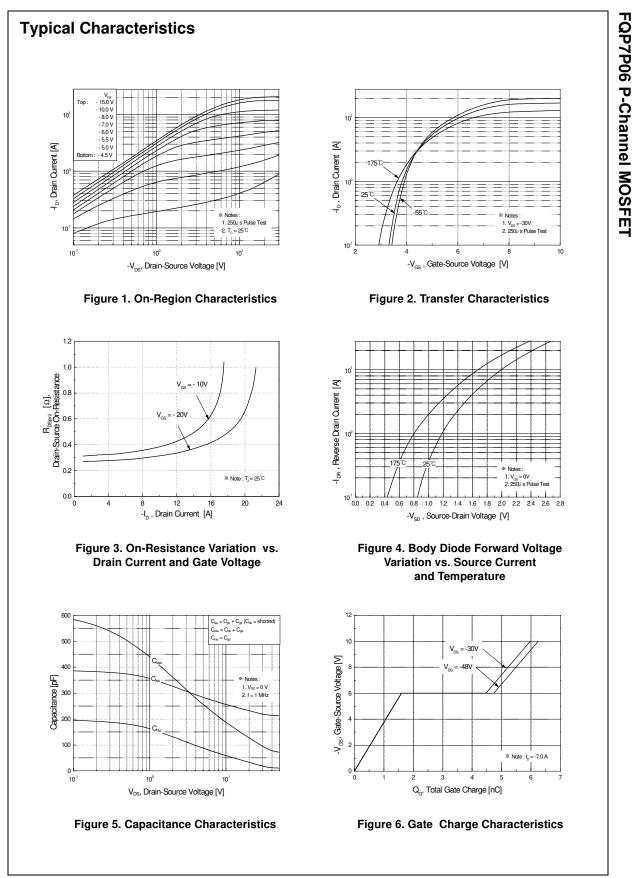
Absolute Maximum Ratings T_c = 25°C unless otherwise noted

Symbol	Parameter		FQP7P06	Unit
V _{DSS}	Drain-Source Voltage		-60	V
I _D	Drain Current - Continuous (T _C = 25°	°C)	-7.0	А
	- Continuous (T _C = 100	0°C)	-4.95	А
I _{DM}	Drain Current - Pulsed	(Note 1)	-28	А
V _{GSS}	Gate-Source Voltage		± 25	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	90	mJ
I _{AR}	Avalanche Current	(Note 1)	-7.0	А
E _{AR}	Repetitive Avalanche Energy	(Note 1)	4.5	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-7.0	V/ns
PD	Power Dissipation (T _C = 25°C) - Derate above 25°C		45	W
			0.3	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C
Τ _L	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

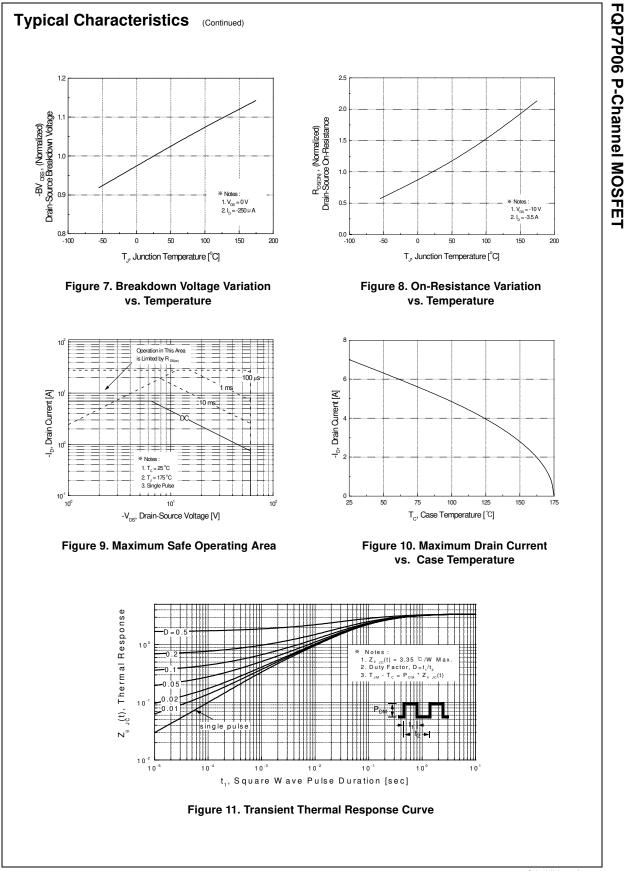
Thermal Characteristics

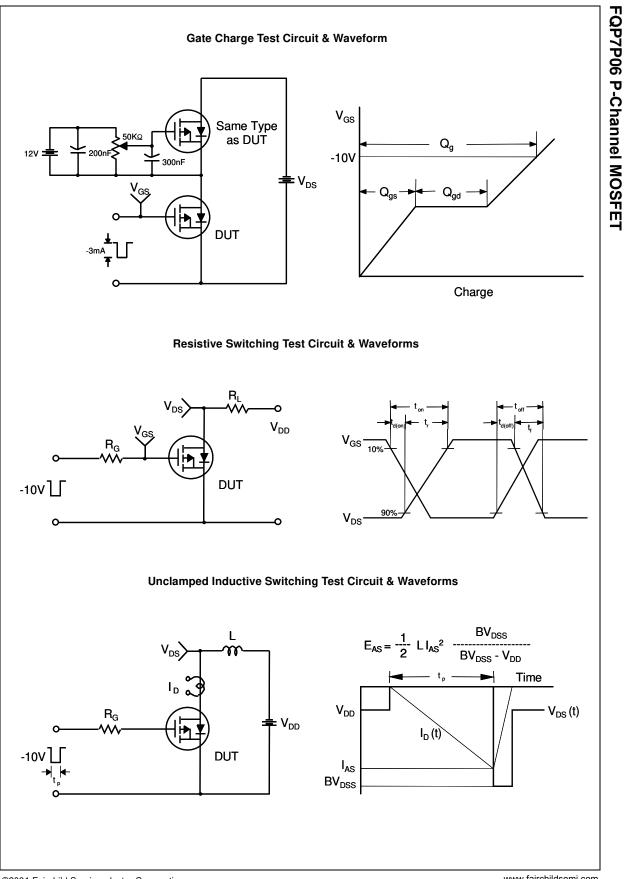
Symbol	Parameter	Тур	Max	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		3.35	°C/W	
R _{0CS} Thermal Resistance, Case-to-Sink		0.5		°C/W	
R _{0JA} Thermal Resistance, Junction-to-Ambient			62.5	°C/W	

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Off Cha	racteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = -250 μA				V
ΔBV _{DSS} / ΔTJ	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, Referenced to 25°C	-60	-0.07		V/°C
I _{DSS}		V _{DS} = -60 V, V _{GS} = 0 V			-1	μA
	Zero Gate Voltage Drain Current $V_{DS} = -48 \text{ V}, T_C = 150^{\circ}\text{C}$				-10	μΑ
GSSF	Gate-Body Leakage Current, Forward	$V_{GS} = -25 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = 25 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
On Cha	racteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-2.0		-4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -3.5 \text{ A}$		0.32	0.41	Ω
ĴFS	Forward Transconductance	V _{DS} = -30 V, I _D = -3.5 A (Note 4)		4.0		S
		50 5				
-	c Characteristics	1			r	T.
C _{iss}	Input Capacitance	$V_{DS} = -25 V, V_{GS} = 0 V,$		225	295	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		110	145	pF
C _{rss}	Reverse Transfer Capacitance	1		25	32	pF
d(on) r	ng Characteristics Turn-On Delay Time Turn-On Rise Time	$V_{DD} = -30 \text{ V}, \text{ I}_{D} = -3.5 \text{ A},$		7 50	25 110	ns ns
		R _G = 25 Ω				
d(off) f	Turn-Off Delay Time Turn-Off Fall Time	(Note 4, 5)		7.5 25	25 60	ns ns
τ Ω _g	Total Gate Charge	· · ·		6.3	8.2	nC
•	-	$V_{DS} = -48 \text{ V}, \text{ I}_{D} = -7.0 \text{ A},$		1.6		
ຊ _{gs} ຊ _{gd}	Gate-Source Charge Gate-Drain Charge	V _{GS} = -10 V (Note 4, 5)		3.1		nC nC
∡ga	Gale-Dialit Gliarge	(1000-1,0)		0.1		10
Drain-S	ource Diode Characteristics ar	nd Maximum Ratings				
S	Maximum Continuous Drain-Source Dic	Aximum Continuous Drain-Source Diode Forward Current			-7.0	Α
SM	Aximum Pulsed Drain-Source Diode Forward Current				-28	Α
√ _{SD}	Drain-Source Diode Forward Voltage				-4.0	V
rr	Reverse Recovery Time	$V_{GS} = 0 V, I_{S} = -7.0 A,$		77		ns
ຊ _{rr}	Reverse Recovery Charge	$dI_F / dt = 100 \text{ A}/\mu \text{s} \qquad (\text{Note 4})$		0.23		μC
L = 2.1mH, I I _{SD} ≤ -7.0A, Pulse Test :	ating : Pulse width limited by maximum junction temper $A_S = -7.0A$, $V_{DD} = -25V$, $R_G = 25 \Omega$, Starting $T_J = 25^{\circ}C$ di/dt $\leq 300A/\mu$ s, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^{\circ}C$ Pulse width $\leq 300\mu$ s, Duty cycle $\leq 2\%$ idependent of operating temperature					



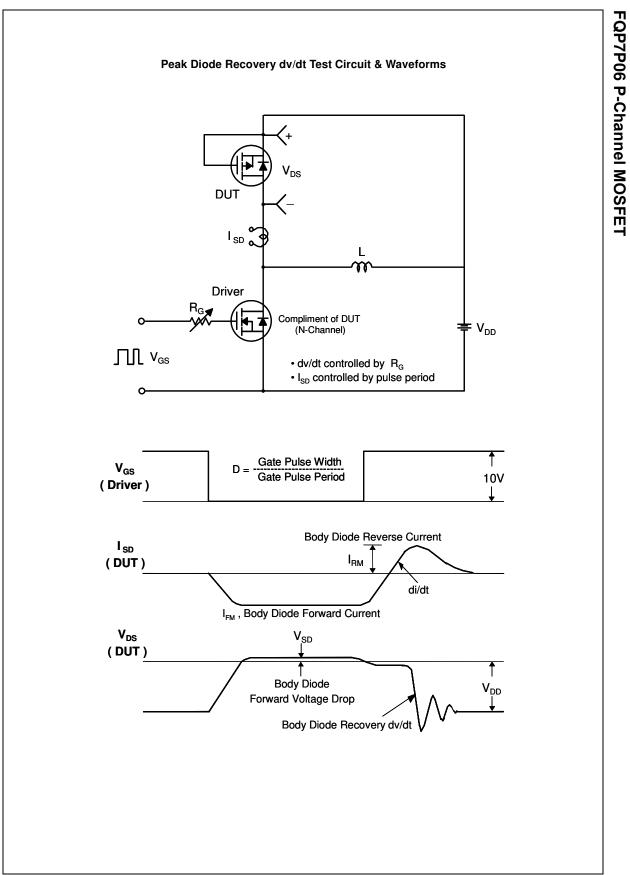
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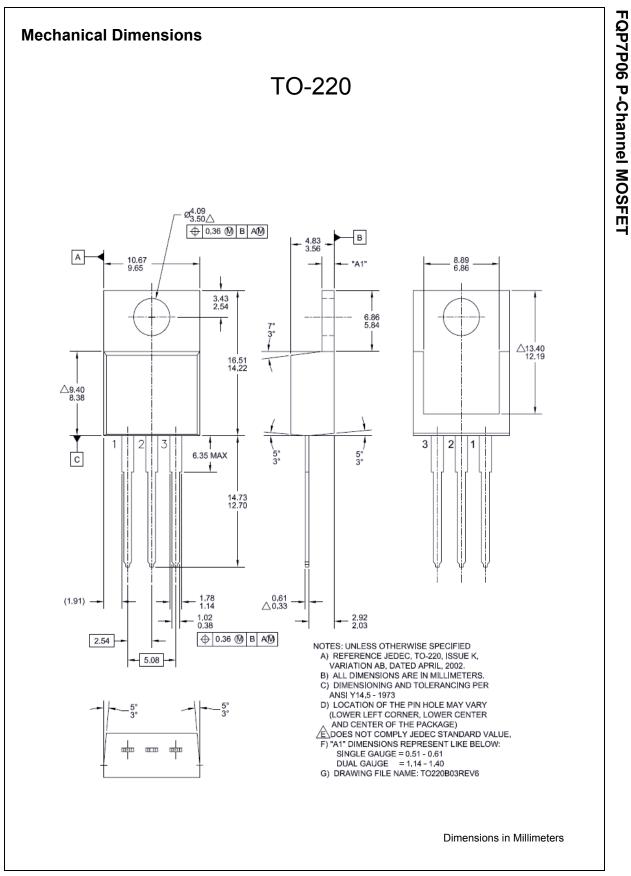




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